

T495X686K025ATE200

T495, Tantalum, MnO2 Tantalum, 68 uF, 10%, 25 VDC, SMD, MnO2, Molded, Low ESR, 200 mOhms, 7343, Height Max = 4.3mm

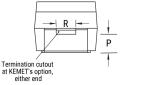
CATHODE (-) END VIEW



ANODE (+) END VIEW



SIDE VIEW



Click	here fo	r the 3D	model.
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Dimensions	
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	4mm +/-0.3mm
Т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
А	3.6mm MIN
В	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
Р	1.7mm REF
R	1mm REF
Х	0.1mm +/-0.1mm

Т

Packaging Specifications			
Packaging	T&R, 178mm		
Packaging Quantity	500		

General Information	
Series	T495
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR
Features	Low ESR
RoHS	Yes
Termination	Tin
AEC-Q200	No
Component Weight	652.04 mg
Shelf Life	156 Weeks
MSL	1

Specifications			
Capacitance	68 uF		
Capacitance Tolerance	10%		
Voltage DC	25 VDC (85C), 16.75 VDC (125C)		
Temperature Range	-55/+125°C		
Rated Temperature	85°C		
Dissipation Factor	6% 120Hz 25C		
Failure Rate	N/A		
Resistance	200 mOhms (100kHz 25C)		
Ripple Current	908 mA (rms, 100kHz 25C), 817.2 mA (rms, 85C), 363.2 mA (rms, 125C)		
Leakage Current	17 uA (5min 25°C)		

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